Silicon Carbide Schottky Diode

650 V, 10 A

FFSD1065A

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 64 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

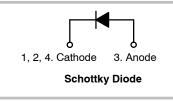
Applications

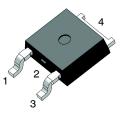
- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



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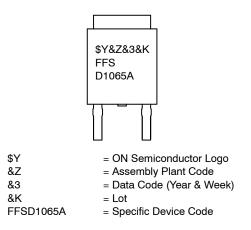
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DPAK3 (TO-252, 3 LD) CASE 369AS





ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSD1065A

Symbol	Rating Parameter		FFSD1065A	Unit
V _{RRM}	Peak Repetitive Reverse Voltage		650	V
E _{AS}	Single Pulse Avalanche Energy (Note 1)		64	mJ
١ _F	Continuous Rectified Forward Current @ T _C < 158°C		10	Α
	Continuous Rectified Forward Current @ T _C < 135°C		18	
I _{F,MAX}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	760	Α
		T _C = 150°C, 10 μs	740	Α
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, tp = 8.3 ms	56	Α
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, tp = 8.3 ms	34	A
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	150	W
		T _C = 150°C	25	W
T _J . T _{STG}	Operating and Storage Temperature Range		–55 to + 175	°C

MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.0	°C/W

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
OFF CHAR	ACTERISTICS				•	-
V _F	Forward Voltage	$I_{F} = 10 \text{ A}, T_{C} = 25^{\circ}\text{C}$	-	1.50	1.75	V
		$I_{F} = 10 \text{ A}, T_{C} = 125^{\circ}\text{C}$	-	1.6	2.0	
		$I_{F} = 10 \text{ A}, T_{C} = 175^{\circ}\text{C}$	-	1.72	2.4	
I _R	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	-	200	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	-	400	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	-	600	
Q _C	Total Capacitive Charge	V = 400 V	-	34	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	575	-	pF
		V _R = 200 V, f = 100 kHz	-	62	-	
		V _R = 400 V, f = 100 kHz	-	47	-	

1. E_{AS} of 64 mJ is based on starting T_J = 25°C; L = 0.5 mH, I_{AS} = 16 A, V = 50 V.

ORDERING INFORMATION

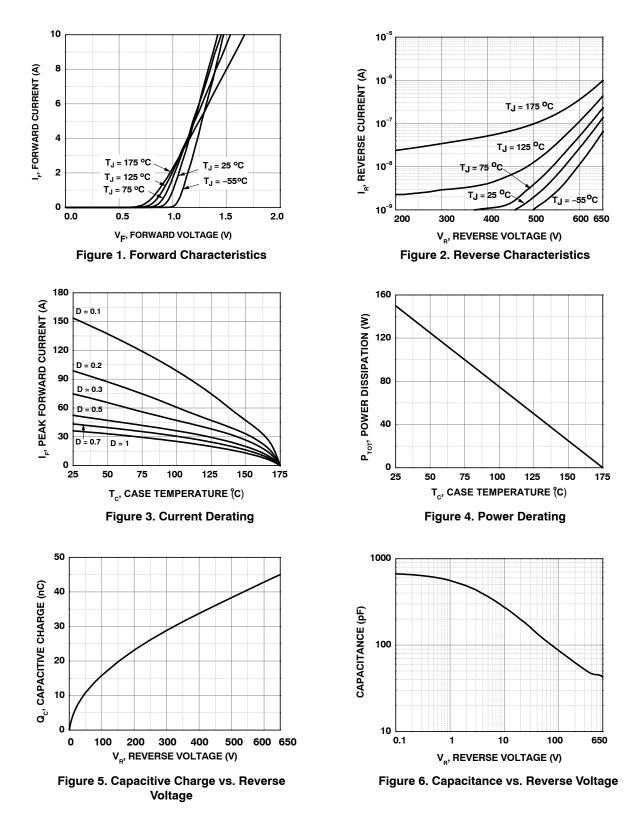
Device	Marking	Package	Reel Size [†]	Tape Width	Quantity
FFSD1065A	FFSD1065A	DPAK3	13″	N/A	2500

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

FFSD1065A

TYPICAL CHARACTERISTICS

(T_J = 25° C unless otherwise noted)



FFSD1065A

TYPICAL CHARACTERISTICS (continued)

(T_J = 25°C unless otherwise noted)

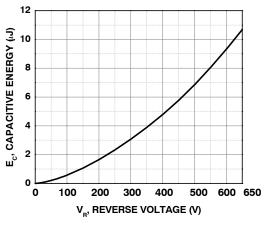


Figure 7. Capacitance Stored Energy

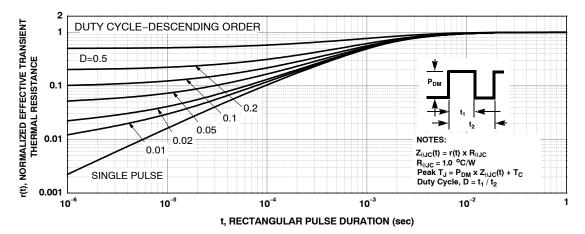
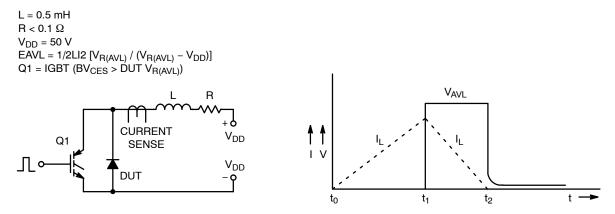


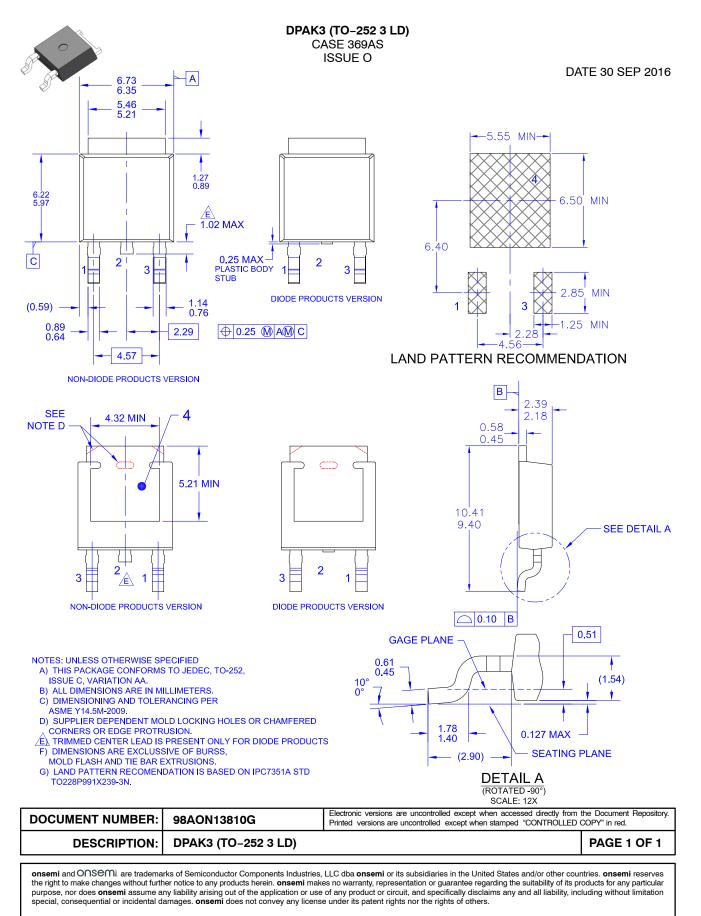
Figure 8. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS





MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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